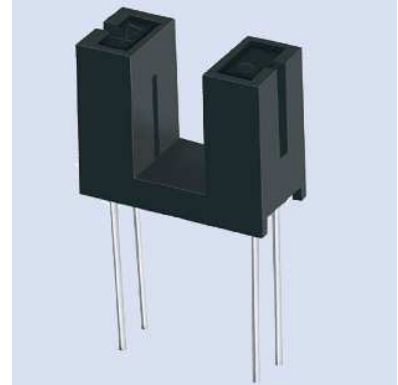


Technical Data Sheet

Opto Interrupter SGM9608

■ Features

- Fast response time
- High analytic
- Peak wavelength $\lambda_p=940\text{nm}$
- High sensitivity
- Pb free



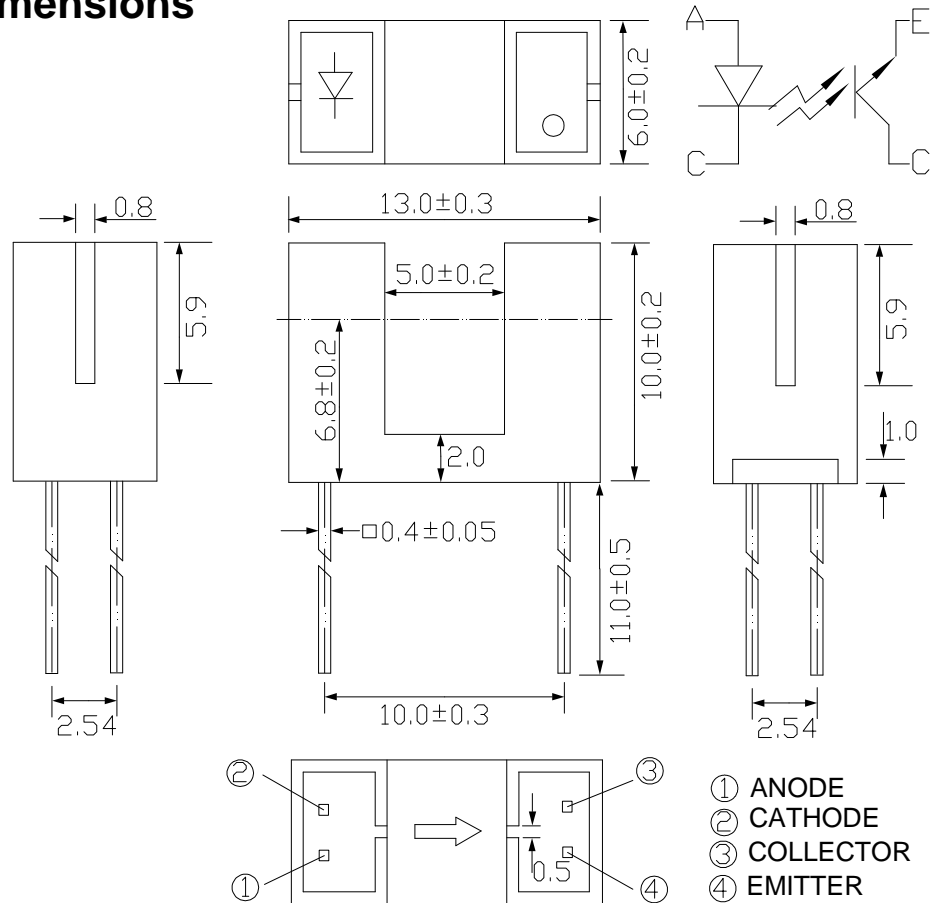
■ Descriptions

The SGM9608 consist of an infrared emitting diode and an NPN silicon phototransistor,encased side-by-side on converging optical axis in a black thermoplastic housing . The phototransistor receives radiation from the IR LED only. This is the normal situation. But when an object is in between , phototransistor could not receives the radiation.

■ Applications

- Non-contact Switching
- Switch Scanner
- For Direct Board
- Floppy disk driver

Package Dimensions



Note: 1. All dimensions are in millimeters
 2. Tolerances unless dimensions ± 0.3mm

Absolute Maximum Ratings (Ta=25°C)

| Parameter | | Symbol | Rating | Units |
|---------------------------------|---|--------|-----------|-------|
| Input | Power Dissipation at(or below) 25°C Free Air Temperature | Pd | 75 | mW |
| | Reverse Voltage | VR | 5 | V |
| | Continuous Forward Current | IF | 50 | mA |
| | Peak Forward Current (*1) | IFP | 0.5 | A |
| Output | Collector Power Dissipation | Pd | 75 | mW |
| | Collector Current | Ic | 20 | mA |
| | Collector-Emitter Voltage | VCEO | 30 | V |
| | Emitter-Collector-Voltage | VECO | 5 | V |
| Lead Soldering Temperature (*2) | | Tsol | 260 | °C |
| Operating Temperature | | Topr | -25 ~ +85 | °C |
| Storage Temperature | | Tstg | -40 ~ +85 | °C |

Notes: *1:IFP Conditions--Pulse Width ≤ 100 μs and Duty ≤ 1%.

*2:Soldering time ≤ 5 seconds.

■ **Electro-Optical Characteristics (Ta=25°C)**

| Parameter | | Symbol | Min. | Typ. | Max. | Units | Conditions |
|--------------------------|------------------------|----------------------|------|------|------|-------|---|
| Input | Forward Voltage | V _F | -- | 1.2 | 1.5 | V | I _F =20mA |
| | Reverse Current | I _R | -- | -- | 10 | μA | V _R =5V |
| | Peak Wavelength | λ _p | -- | 940 | -- | nm | I _F =20mA |
| | View Angle | 2θ 1/2 | -- | 60 | -- | Deg | I _F =20mA |
| Output | Dark Current | I _{CEO} | -- | -- | 100 | nA | V _{CE} =20V, E _e =0mw/cm ² |
| | C-E Saturation Voltage | V _{CE (S)} | - | -- | 0.4 | V | I _C =2mA, E _e =1mw/cm ² |
| Transfer Characteristics | Collector Current | I _{C (ON)} | 0.5 | -- | 10 | mA | V _{CE} =5V, I _F =20mA |
| | | I _{C (OFF)} | -- | -- | 20 | μA | |
| | Rise Time | t _r | -- | 15 | | μS | V _{CE} =5V, I _C =1mA |
| | Fall Time | t _f | -- | 15 | | μS | R _L =1000 |

■ **Typical Electro-Optical Characteristics Curves for IR**

Fig.1 Forward Current vs. Ambient Temperature

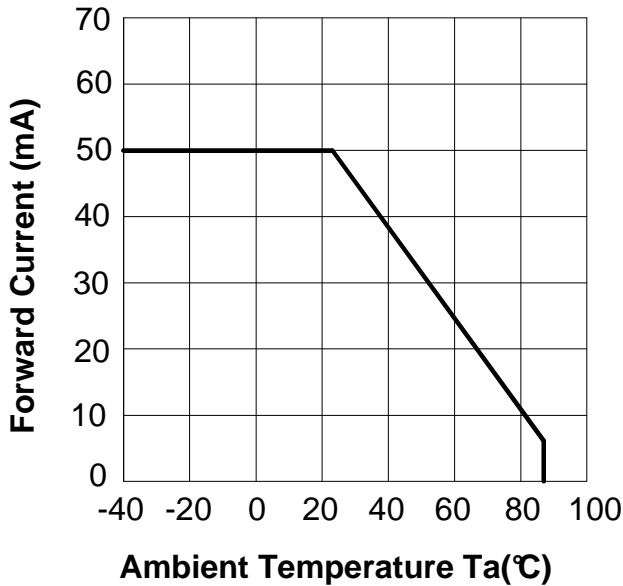


Fig.2 Spectral Distribution

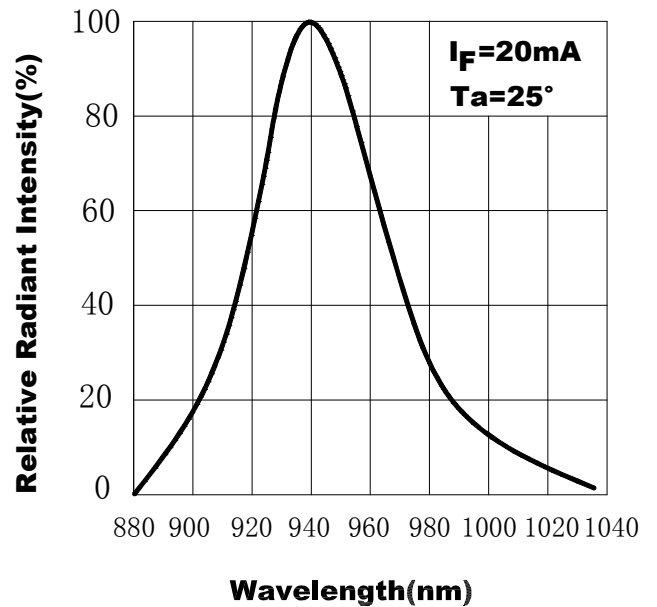


Fig.3 Peak Emission Wavelength vs. Ambient Temperature

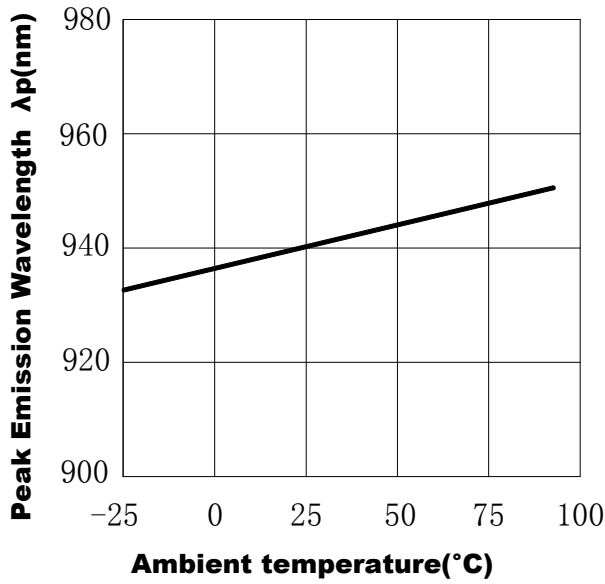


Fig.4 Forward Current vs. Forward Voltage

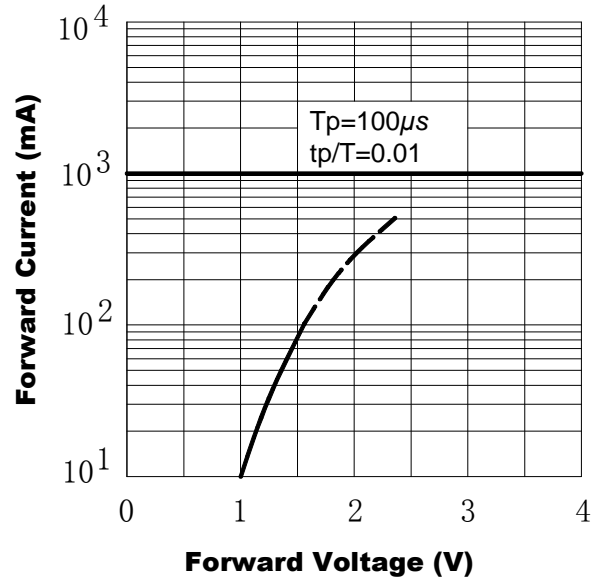


Fig.5 Radiant Intensity vs. Forward Current

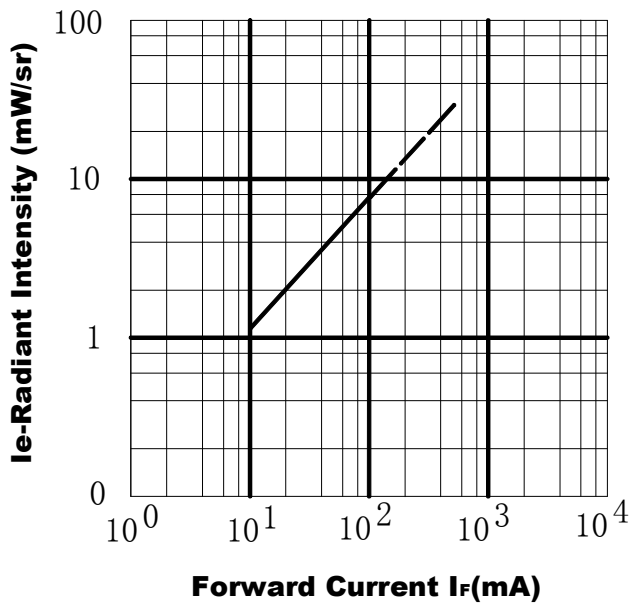
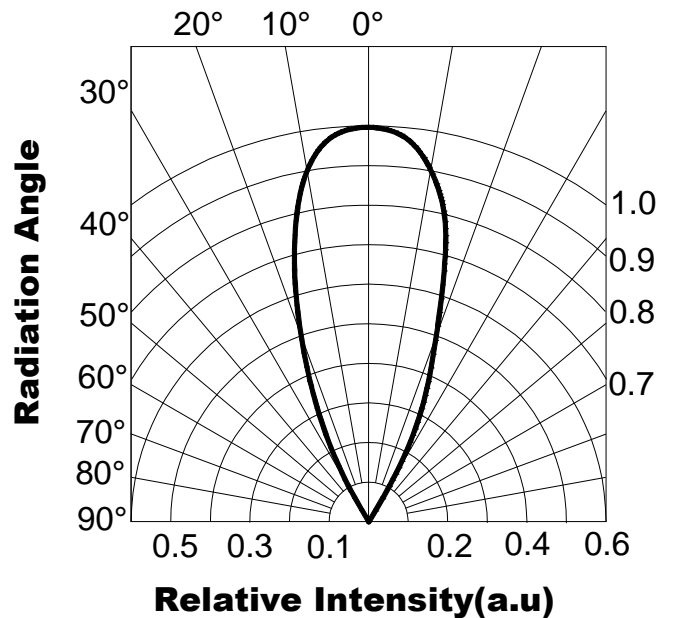


Fig.6 Relative Radiant Intensity vs. Angular Displacement



■ Typical Electro-Optical Characteristics Curves for PT

Fig.1 Collector Power Dissipation vs. Ambient Temperature

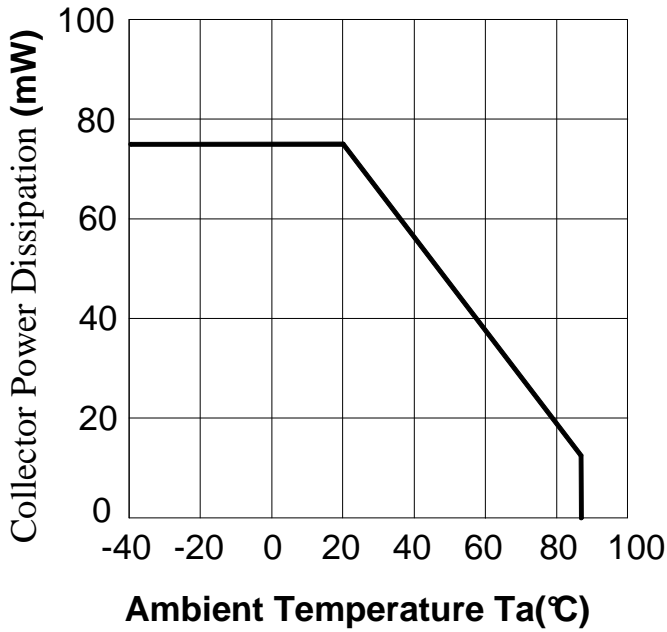


Fig.2 Spectral Sensitivity

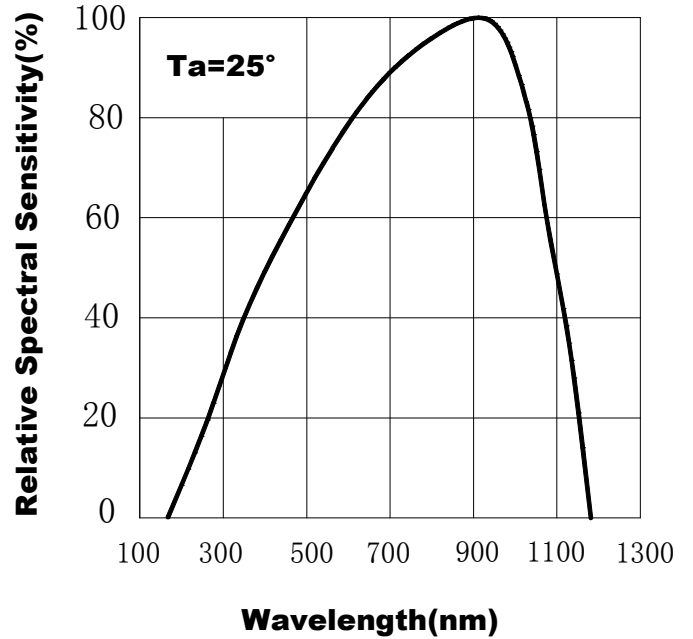


Fig.3 Relative Collector Current vs. Ambient Temperature

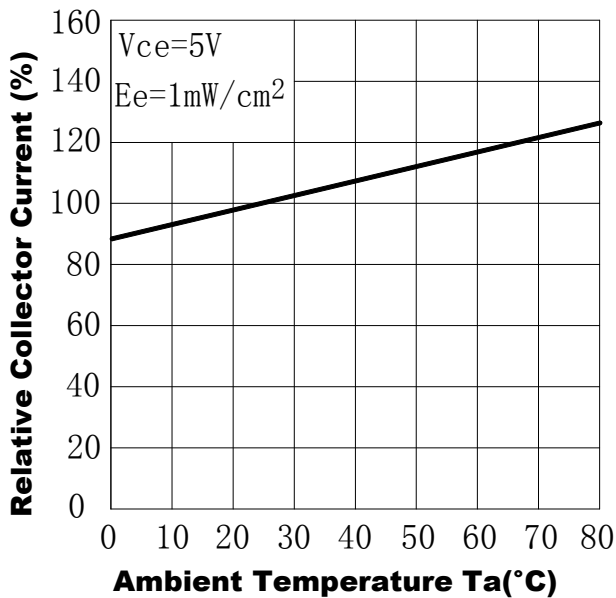


Fig.4 Collector Current vs. Irradiance

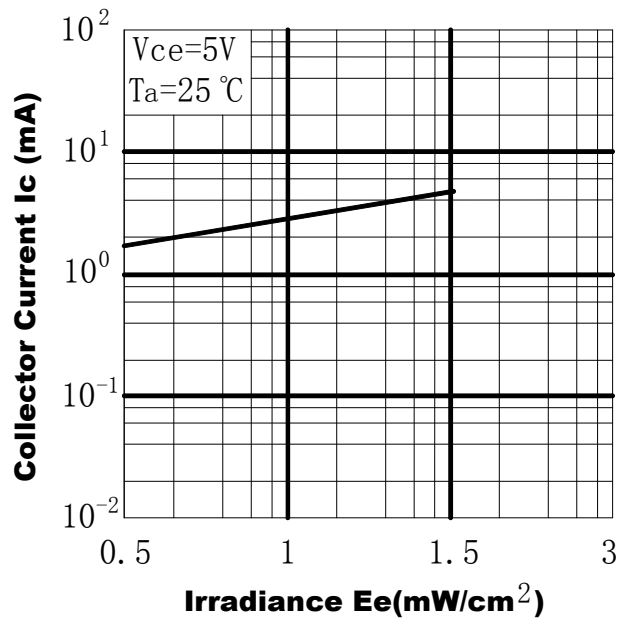


Fig.5 Collector Dark Current vs. Ambient Temperature

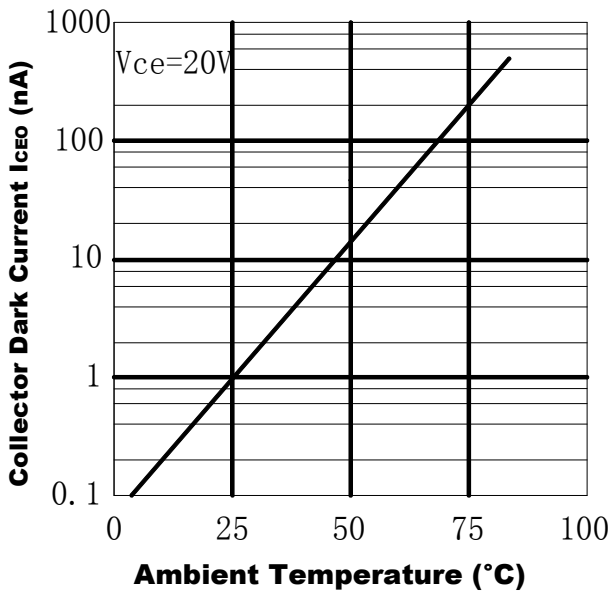
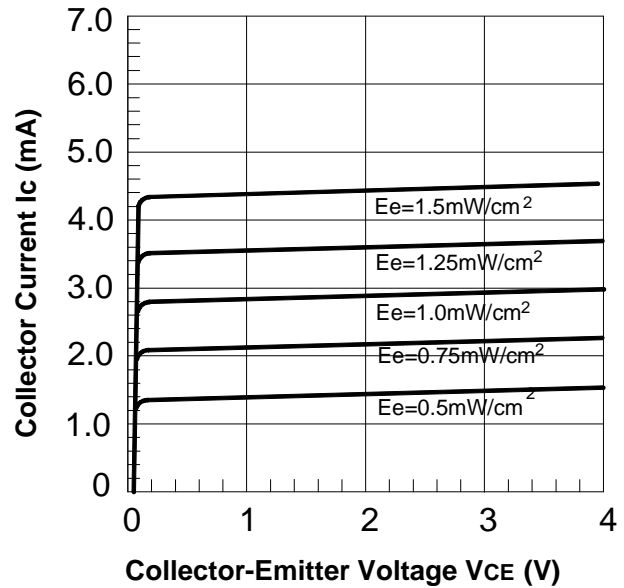


Fig.6 Collector Current vs. Collector-Emitter Voltage



■ **Packing Quantity Specification**

1. 100PCS/1Bag

■ **Notes**

1. Above specification may be changed without notice. SHUGUAN will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. SHUGUAN assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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